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PJQ4451EP-AU

40V P-Channel Enhancement Mode MOSFET DFN3333-8L -40 V Current Voltage -60 A **Features** • Rds(on), Vgs@-10V, Id@-10A<9.8mΩ • Rds(ON), Vgs@-4.5V, Id@-6A<14.7mΩ • 100% UIS tested • Reliable and Rugged • AEC-Q101 qualified • Lead free in compliance with EU RoHS 2.0 • Green molding compound as per IEC 61249 standard **Mechanical Data** • Case : DFN3333-8L Package • Terminals : Solderable per MIL-STD-750, Method 2026 • Approx. Weight : 0.03 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-40	V
Gate-Source Voltage		V _{GS}	±25	V
Continuous Drain Current ^(Note 3)	T _C =25°C		-60	
	Tc=100°C	I _D	-42	A
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	-211	
Power Dissipation	T _C =25°C	D _	63	
	Tc=100°C	PD	31	W
Continuous Drain Current ^(Note 4)	T _A =25°C		-12	
	T _A =70°C	I _D	-10	A
Power Dissipation	T _A =25°C	D _	2.5	
	T _A =70°C	PD	1.8	W
Single Pulse Avalanche Energy ^{(Note}	9 5)	Eas	121	mJ
Operating Junction and Storage Temperature Range		TJ,T _{STG}	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	$R_{ extsf{ heta}JC}$	2.4	°C/W
	Junction to Ambient	R _{θJA}	60	C/VV



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static		•					
Drain-Source Breakdown Voltage	BV _{DSS}	ss V _{GS} =0V, I _D =-250uA -4		-	-	Ň	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.9	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	7.8	9.8	mΩ	
		V _{GS} =-4.5V, I _D =-6A	-	11.3	14.7		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-40V, V_{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±25V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)	-			•		-	
Total Gate Charge	Qg	V _{DS} =-32V, I _D =-10A,	-	59	-		
Gate-Source Charge	Qgs		-	9	-	nC	
Gate-Drain Charge	Q_{gd}	V _{GS} =-10V	-	20	-		
Input Capacitance	Ciss		-	3300	-	pF	
Output Capacitance	Coss	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	380	-		
Reverse Transfer Capacitance	Crss	I=IIVIHZ	-	240	-		
Gate resistance	Rg	f=1MHz	-	4	-	Ω	
Turn-On Delay Time	td _(on)		-	13	-		
Turn-On Rise Time	tr	V _{DS} =-32V, I _D =-10A,	-	16	-		
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =3Ω	-	54	-	ns	
Turn-Off Fall Time	tf		-	33	-		
Drain-Source Diode	•						
Diode Forward Current	I _S	Tc=25°C	-	-	-60	•	
Pulsed Diode Forward Current	I _{SM}	1c=25 C	-	-	-211	A	
Diode Forward Voltage	V _{SD}	Is=-20A, V _{GS} =0V	-	-0.85	-1.3	V	
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	23	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	11	-	nC	

NOTES :

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =-22A, V_{DD} =-30V, V_{GS} =-10V, Starting T_J =25°°C.
- 6. Guaranteed by design, not subject to production testing.

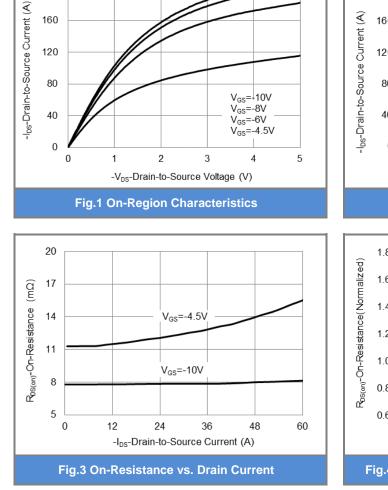
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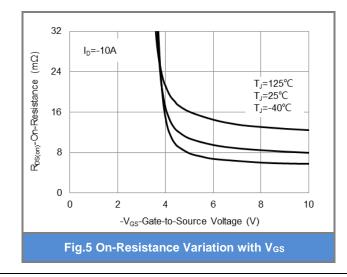
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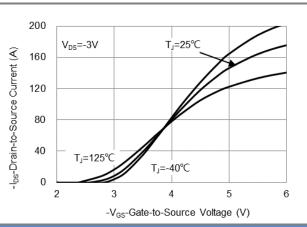


Fig.2 Transfer Characteristics

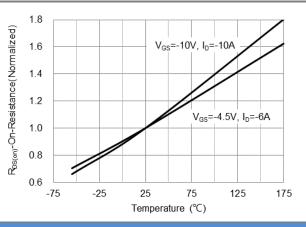
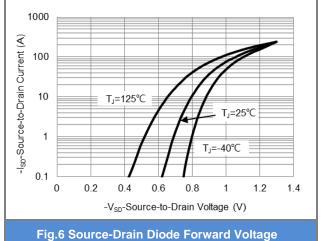


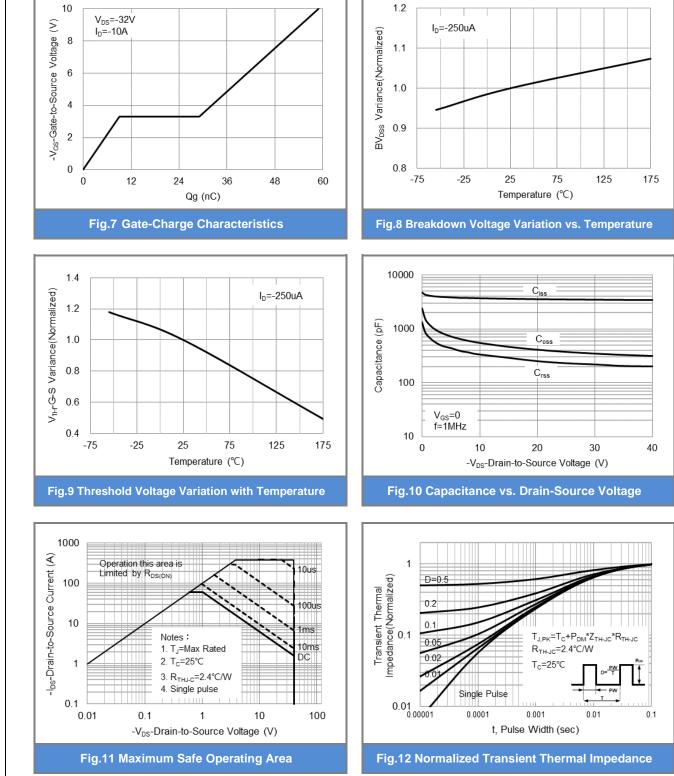
Fig.4 On-Resistance vs. Junction temperature





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PJQ4451EP-AU **TYPICAL CHARACTERISTIC CURVES** 10 V_{DS}=-32V

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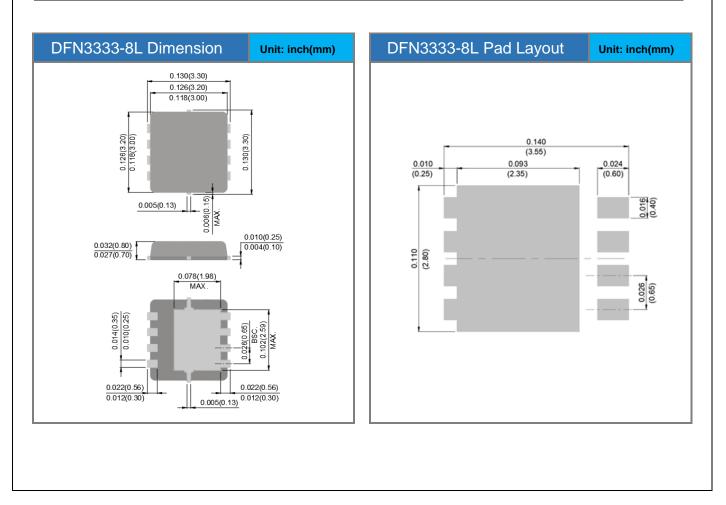


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJQ4451EP-AU	DFN3333-8L	5K pcs / 13" reel	451E	

Packaging Information & Mounting Pad Layout





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